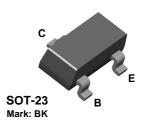


BCX71K



PNP General Purpose Amplifier This device is designed for applications requiring extremely high current gain at collector currents to 300 mA. Sourced from Process 68. Absolute Maximum Ratings* TA=25°C unless otherwise noted				
Symbol	Parameter	Value	Units	
V _{CEO}	Collector-Emitter Voltage	45	V	
V _{CES}	Collector-Base Voltage	45	V	
V _{EBO}	Emitter-Base Voltage	5.0	V	
I _C	Collector Current - Continuous	500	mA	
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- NOTES:

 1) These ratings are based on a maximum junction temperature of 150 degrees C.

 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

 3) All voltages (V) and currents (A) are negative polarity for PNP transistors.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		*BCX71K	
P _D	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

^{*}Device mounted on FR-4 PCB 40 mm X 40 mm X 1.5 mm.

PNP General Purpose Amplifier

(continued)

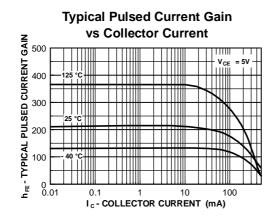
Electrical	Characteristics
FIECTICA	Characteristics

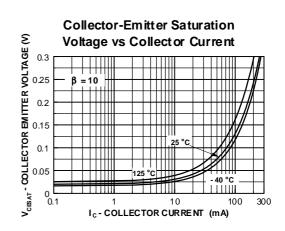
TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
	RACTERISTICS				
		T			
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 1.0 \text{ mA}, I_B = 0$	45		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5.0		V
I _{CES}	Collector-Cutoff Current	$V_{CB} = 45 \text{ V}, I_{E} = 0$		20	nA
		$V_{CB} = 45 \text{ V}, I_{E} = 0, T_{A} = 100^{\circ}\text{C}$		20	μΑ
	ACTEDICTION				
	ACTERISTICS	I	400		ı
h _{FE}	DC Current Gain	$I_C = 10 \mu A, V_{CE} = 5.0 V$ $I_C = 2.0 \text{ mA}, V_{CE} = 5.0 V$	100 380	630	
		$I_C = 2.0 \text{ mA}, V_{CE} = 3.0 \text{ V}$ $I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$	110	630	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 0.25 \text{ mA}$	0.06	0.25	V
V CE(Sat)	Composition Emmission Community of the grant	$I_C = 50 \text{ mA}, I_B = 1.25 \text{ mA}$	0.12	0.55	V
√ _{BE(sat)}	Base-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 0.25 \text{ mA}$	0.6	0.85	V
()	-	$I_C = 50 \text{ mA}, I_B = 1.25 \text{ mA}$	0.68	1.05	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	0.6	0.75	V
SMALL SI	GNAL CHARACTERISTICS	The same			
C _{obo}	Output Capacitance	$V_{CE} = 10 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz}$		6.0	pF
NF	Noise Figure	$I_C = 0.2 \text{ mA}, V_{CE} = 5.0 \text{ V},$		6.0	dB
		$R_S = 2.0 \text{ k}\Omega, f = 1.0 \text{ kHz},$ BW = 200 Hz			
SWITCHI	NG CHARACTERISTICS				
t _(on)	Turn-On Time	$I_C = 10 \text{ mA}, I_{B1} = 1.0 \text{ mA}$		150	ns
t(off)	Turn-Off Time	$I_{B2} = 1.0 \text{ mA}, V_{BB} = 3.6 \text{ V},$ R1 = R2 = 5.0 kΩ, R ₁ = 990 Ω		800	ns

NOTE: All voltages (V) and currents (A) are negative polarity for PNP transistors.

Typical Characteristics

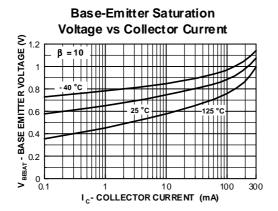


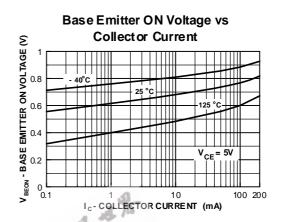


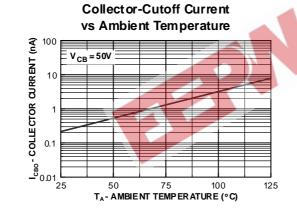
PNP General Purpose Amplifier

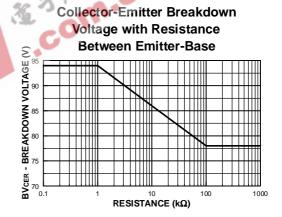
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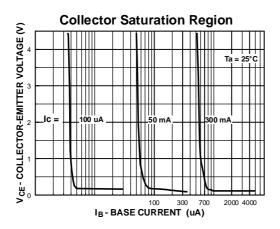
Typical Characteristics (continued)

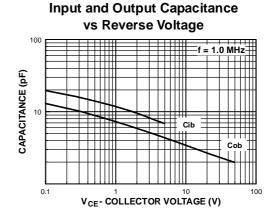








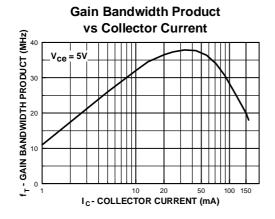


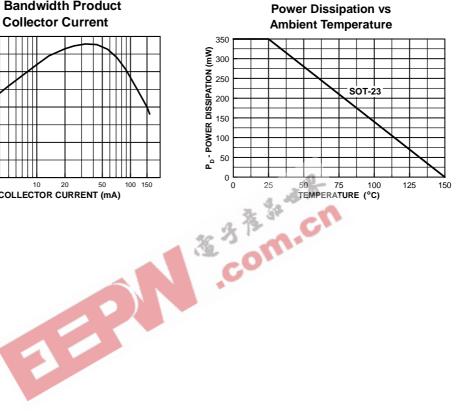


PNP General Purpose Amplifier

(continued)

Typical Characteristics (continued)





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PACMAN™	SuperSOT™-6	
POP™	SuperSOT™-8	
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